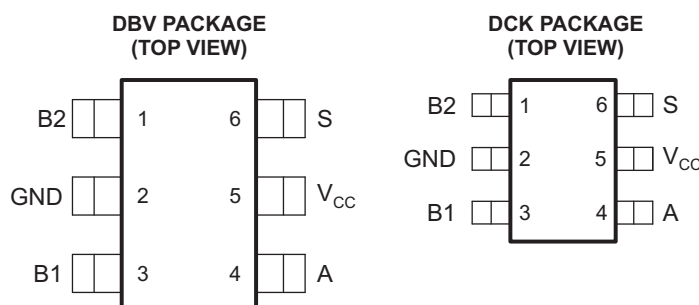


## FEATURES

- **Qualification in Accordance With AEC-Q100<sup>(1)</sup>**
  - **Qualified for Automotive Applications**
  - **Customer-Specific Configuration Control Can Be Supported Along With Major-Change Approval**
  - **ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)**
  - **1.65-V to 5.5-V  $V_{CC}$  Operation**
  - **Useful for Both Analog and Digital Applications**
  - **Specified Break-Before-Make Switching**
  - **Rail-to-Rail Signal Handling**
  - **High Degree of Linearity**
  - **High Speed, Typically 0.5 ns ( $V_{CC} = 3\text{ V}$ ,  $C_L = 50\text{ pF}$ )**
  - **Low On-State Resistance, Typically  $\approx 6\ \Omega$  ( $V_{CC} = 4.5\text{ V}$ )**
  - **Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II**
- (1) Contact factory for details. Q100 qualification data available on request.



See mechanical drawings for dimensions.

## DESCRIPTION/ORDERING INFORMATION

This single-pole double-throw (SPDT) analog switch is designed for 1.65-V to 5.5-V  $V_{CC}$  operation.

The SN74LVC1G3157 can handle both analog and digital signals. The device permits signals with amplitudes of up to  $V_{CC}$  (peak) to be transmitted in either direction.

Applications include signal gating, chopping, modulation or demodulation (modem), and signal multiplexing for analog-to-digital and digital-to-analog conversion systems.

## ORDERING INFORMATION

$T_A$	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 125°C	SOT (SOT-23) – DBV	Reel of 3000	1P1G3157QDBVRQ1	CC50
	SOT (SC-70) – DCK	Reel of 3000	1P1G3157QDCKRQ1	C50

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).

## FUNCTION TABLE

CONTROL INPUTS	ON CHANNEL
L	B1
H	B2



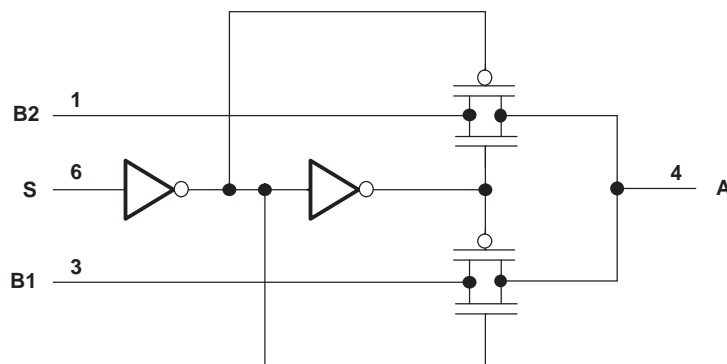
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

# SN74LVC1G3157-Q1

## SINGLE-POLE DOUBLE-THROW ANALOG SWITCH

SCES463D–JUNE 2003–REVISED SEPTEMBER 2006

**LOGIC DIAGRAM (POSITIVE LOGIC)**



### Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range <sup>(2)</sup>		−0.5	6.5	V
V <sub>IN</sub>	Control input voltage range <sup>(2)(3)</sup>		−0.5	6.5	V
V <sub>I/O</sub>	Switch I/O voltage range <sup>(2)(3)(4)(5)</sup>		−0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Control input clamp current	V <sub>IN</sub> < 0	−50		mA
I <sub>IOK</sub>	I/O port diode current	V <sub>I/O</sub> < 0	−50		mA
I <sub>I/O</sub>	On-state switch current	V <sub>I/O</sub> = 0 to V <sub>CC</sub> <sup>(6)</sup>	±128		mA
Continuous current through V <sub>CC</sub> or GND			±100		mA
θ <sub>JA</sub>	Package thermal impedance <sup>(7)</sup>	DBV package	165		°C/W
		DCK package	258		
T <sub>stg</sub>	Storage temperature range		−65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages are with respect to ground, unless otherwise specified.
- (3) The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (4) This value is limited to 5.5 V maximum.
- (5)  $V_I$ ,  $V_O$ ,  $V_A$ , and  $V_{Bn}$  are used to denote specific conditions for  $V_{I/O}$ .
- (6)  $I_I$ ,  $I_O$ ,  $I_A$ , and  $I_{Bn}$  are used to denote specific conditions for  $I_{I/O}$ .
- (7) The package thermal impedance is calculated in accordance with JESD 51-7.

## Recommended Operating Conditions<sup>(1)</sup>

			MIN	MAX	UNIT
V <sub>CC</sub>			1.65	5.5	V
V <sub>I/O</sub>			0	V <sub>CC</sub>	V
V <sub>IN</sub>			0	5.5	V
V <sub>IH</sub>	High-level input voltage, control input	V <sub>CC</sub> = 1.65 V to 1.95 V	V <sub>CC</sub> × 0.75		V
		V <sub>CC</sub> = 2.3 V to 5.5 V	V <sub>CC</sub> × 0.7		
V <sub>IL</sub>	Low-level input voltage, control input	V <sub>CC</sub> = 1.65 V to 1.95 V	V <sub>CC</sub> × 0.25		V
		V <sub>CC</sub> = 2.3 V to 5.5 V	V <sub>CC</sub> × 0.3		
Δt/Δv	Input transition rise/fall time	V <sub>CC</sub> = 1.65 V to 1.95 V	20		ns/V
		V <sub>CC</sub> = 2.3 V to 2.7 V	20		
		V <sub>CC</sub> = 3 V to 3.6 V	10		
		V <sub>CC</sub> = 4.5 V to 5.5 V	10		
T <sub>A</sub>			−40	125	°C

- (1) All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

# SN74LVC1G3157-Q1

## SINGLE-POLE DOUBLE-THROW ANALOG SWITCH

SCES463D–JUNE 2003–REVISED SEPTEMBER 2006

### Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		V <sub>CC</sub>	MIN	TYP <sup>(1)</sup>	MAX	UNIT
r <sub>on</sub>	On-state switch resistance <sup>(2)</sup>	See Figure 1 and Figure 2	V <sub>I</sub> = 0 V, I <sub>O</sub> = 4 mA	1.65 V	11		20	Ω
			V <sub>I</sub> = 1.65 V, I <sub>O</sub> = –4 mA		15		50	
			V <sub>I</sub> = 0 V, I <sub>O</sub> = 8 mA	2.3 V	8		12	
			V <sub>I</sub> = 2.3 V, I <sub>O</sub> = –8 mA		11		30	
			V <sub>I</sub> = 0 V, I <sub>O</sub> = 24 mA	3 V	7		9.5	
			V <sub>I</sub> = 3 V, I <sub>O</sub> = –24 mA		9		20	
			V <sub>I</sub> = 0 V, I <sub>O</sub> = 30 mA	4.5 V	6		7.5	
			V <sub>I</sub> = 2.4 V, I <sub>O</sub> = –30 mA		7		12	
			V <sub>I</sub> = 4.5 V, I <sub>O</sub> = –30 mA		7		15	
r <sub>range</sub>	On-state switch resistance over signal range <sup>(2)(3)</sup>	0 ≤ V <sub>Bn</sub> ≤ V <sub>CC</sub> (see Figure 1 and Figure 2)	I <sub>A</sub> = –4 mA	1.65 V			140	Ω
			I <sub>A</sub> = –8 mA	2.3 V			45	
			I <sub>A</sub> = –24 mA	3 V			18	
			I <sub>A</sub> = –30 mA	4.5 V			10	
Δr <sub>on</sub>	Difference in on-state resistance between switches <sup>(2)(4)(5)</sup>	See Figure 1	V <sub>Bn</sub> = 1.15 V, I <sub>A</sub> = –4 mA	1.65 V		0.5		Ω
			V <sub>Bn</sub> = 1.6 V, I <sub>A</sub> = –8 mA	2.3 V		0.1		
			V <sub>Bn</sub> = 2.1 V, I <sub>A</sub> = –24 mA	3 V		0.1		
			V <sub>Bn</sub> = 3.15 V, I <sub>A</sub> = –30 mA	4.5 V		0.1		
r <sub>on(flat)</sub>	On-state resistance flatness <sup>(2)(4)(6)</sup>	0 ≤ V <sub>Bn</sub> ≤ V <sub>CC</sub>	I <sub>A</sub> = –4 mA	1.65 V			110	Ω
			I <sub>A</sub> = –8 mA	2.3 V			26	
			I <sub>A</sub> = –24 mA	3 V			9	
			I <sub>A</sub> = –30 mA	4.5 V			4	
I <sub>off</sub> <sup>(7)</sup>	Off-state switch leakage current	0 ≤ V <sub>I</sub> , V <sub>O</sub> ≤ V <sub>CC</sub> (see Figure 3)		1.65 V to 5.5 V		±1 ±0.05 ±1 <sup>(1)</sup>		μA
I <sub>S(on)</sub>	On-state switch leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND, V <sub>O</sub> = Open (see Figure 4)		5.5 V		±1 ±0.1 <sup>(1)</sup>		μA
I <sub>IN</sub>	Control input current	0 ≤ V <sub>IN</sub> ≤ V <sub>CC</sub>		0 V to 5.5 V		±1 ±0.05 ±1 <sup>(1)</sup>		μA
I <sub>CC</sub>	Supply current	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5 V		1	10	μA
ΔI <sub>CC</sub>	Supply-current change	V <sub>IN</sub> = V <sub>CC</sub> – 0.6 V		5.5 V			500	μA
C <sub>in</sub>	Control input capacitance	S		5 V		2.7		pF
C <sub>io(off)</sub>	Switch input/output capacitance	Bn		5 V		5.2		pF
C <sub>io(on)</sub>	Switch input/output capacitance	Bn		5 V		17.3		pF
		A				17.3		

(1) T<sub>A</sub> = 25°C

(2) Measured by the voltage drop between I/O pins at the indicated current through the switch. On-state resistance is determined by the lower of the voltages on the two (A or B) ports.

(3) Specified by design

(4) Δr<sub>on</sub> = r<sub>on(max)</sub> – r<sub>on(min)</sub> measured at identical V<sub>CC</sub>, temperature, and voltage levels

(5) This parameter is characterized, but not tested in production.

(6) Flatness is defined as the difference between the maximum and minimum values of on-state resistance over the specified range of conditions.

(7) I<sub>off</sub> is the same as I<sub>S(off)</sub> (off-state switch leakage current).

## Analog Switch Characteristics

$T_A = 25^\circ\text{C}$

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	$V_{CC}$	TYP	UNIT
Frequency response (switch on) <sup>(1)</sup>	A or Bn	Bn or A	$R_L = 50\ \Omega$ , $f_{in} = \text{sine wave}$ (see Figure 6)	1.65 V	300	MHz
				2.3 V	300	
				3 V	300	
				4.5 V	300	
Crosstalk (between switches) <sup>(2)</sup>	B1 or B2	B2 or B1	$R_L = 50\ \Omega$ , $f_{in} = 10\ \text{MHz}$ (sine wave) (see Figure 7)	1.65 V	–54	dB
				2.3 V	–54	
				3 V	–54	
				4.5 V	–54	
Feedthrough attenuation (switch off) <sup>(2)</sup>	A or Bn	Bn or A	$C_L = 5\ \text{pF}$ , $R_L = 50\ \Omega$ , $f_{in} = 10\ \text{MHz}$ (sine wave) (see Figure 8)	1.65 V	–57	dB
				2.3 V	–57	
				3 V	–57	
				4.5 V	–57	
Charge injection <sup>(3)</sup>	S	A	$C_L = 0.1\ \text{nF}$ , $R_L = 1\ \text{M}\Omega$ (see Figure 9)	3.3 V	3	pC
				5 V	7	
Total harmonic distortion	A or Bn	Bn or A	$V_I = 0.5\ \text{V}_{p-p}$ , $R_L = 600\ \Omega$ , $f_{in} = 600\ \text{Hz}$ to $20\ \text{kHz}$ (sine wave) (see Figure 10)	1.65 V	0.1	%
				2.3 V	0.025	
				3 V	0.015	
				4.5 V	0.01	

(1) Adjust  $f_{in}$  voltage to obtain 0 dBm at output. Increase  $f_{in}$  frequency until dB meter reads –3 dB.

(2) Adjust  $f_{in}$  voltage to obtain 0 dBm at input.

(3) Specified by design

## Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 5 and Figure 11)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 1.8\ \text{V}$ $\pm 0.15\ \text{V}$		$V_{CC} = 2.5\ \text{V}$ $\pm 0.2\ \text{V}$		$V_{CC} = 3.3\ \text{V}$ $\pm 0.3\ \text{V}$		$V_{CC} = 5\ \text{V}$ $\pm 0.5\ \text{V}$		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
$t_{pd}$ <sup>(1)</sup>	A or Bn	Bn or A		2		1.2		0.8		0.3	ns
$t_{en}$ <sup>(2)</sup>	S	Bn	7	24	3.5	14	2.5	7.6	1.7	5.7	ns
$t_{dis}$ <sup>(3)</sup>			3	13	2	7.5	1.5	5.3	0.8	3.8	
$t_{B-M}$ <sup>(4)</sup>			0.5		0.5		0.5		0.5		ns

(1)  $t_{pd}$  is the slower of  $t_{PLH}$  or  $t_{PHL}$ . Propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impedance).

(2)  $t_{en}$  is the slower of  $t_{PZL}$  or  $t_{PZH}$ .

(3)  $t_{dis}$  is the slower of  $t_{PLZ}$  or  $t_{PHZ}$ .

(4) Specified by design

## PARAMETER MEASUREMENT INFORMATION

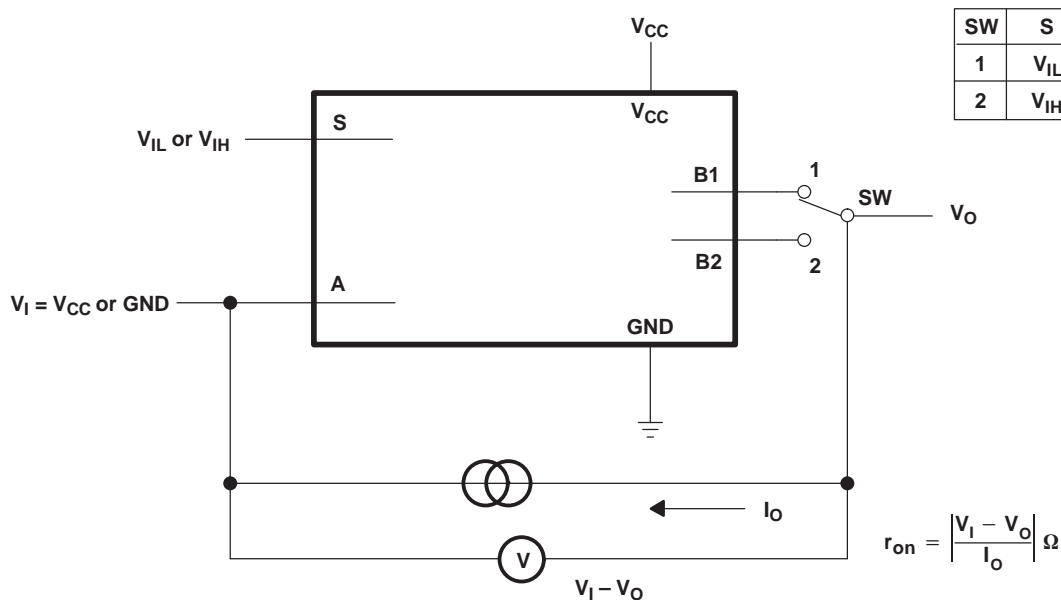


Figure 1. On-State Resistance Test Circuit

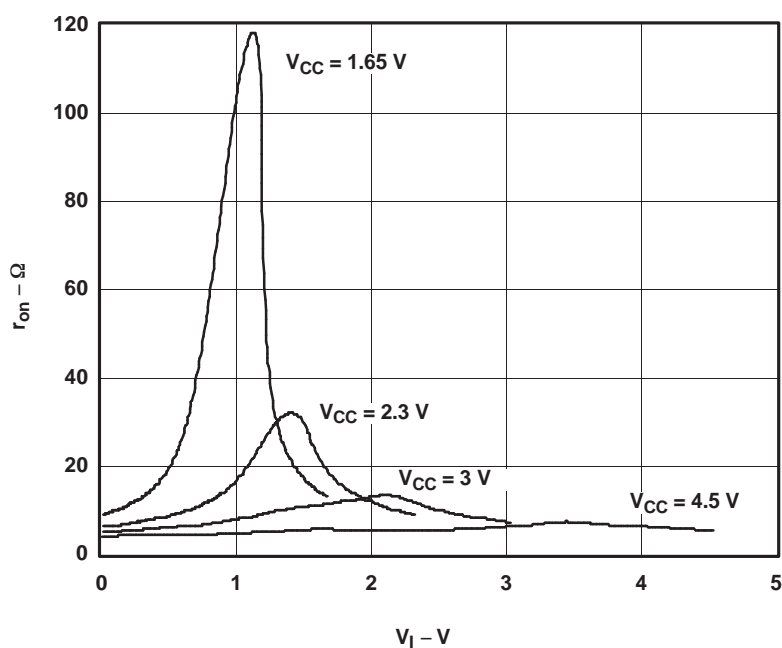
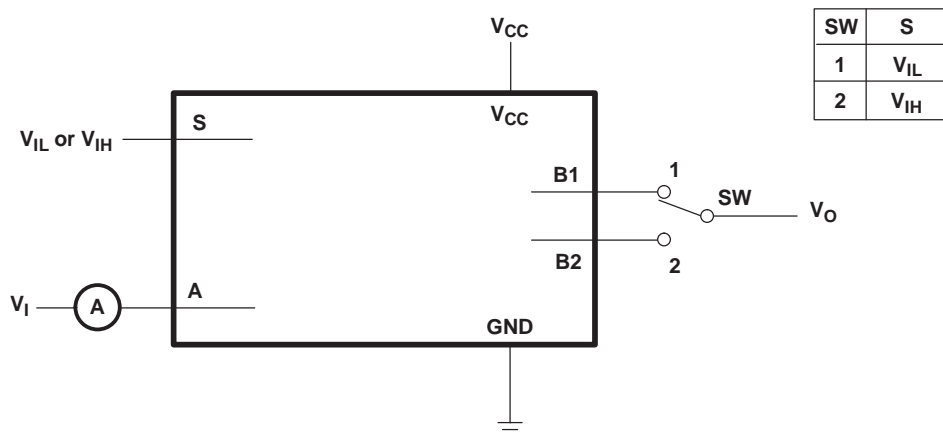


Figure 2. Typical  $r_{on}$  as a Function of Input Voltage ( $V_I$ ) for  $V_I = 0$  to  $V_{CC}$

PARAMETER MEASUREMENT INFORMATION (continued)



Condition 1:  $V_I = \text{GND}$ ,  $V_O = V_{CC}$   
Condition 2:  $V_I = V_{CC}$ ,  $V_O = \text{GND}$

Figure 3. Off-State Switch Leakage-Current Test Circuit

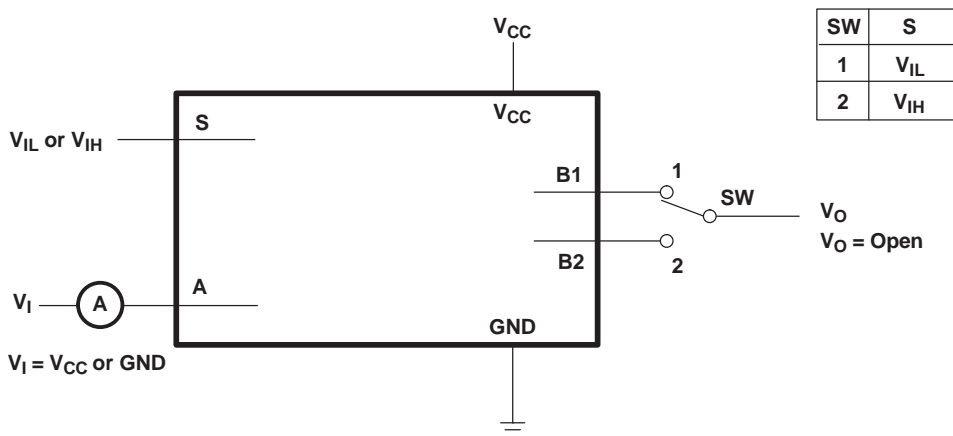
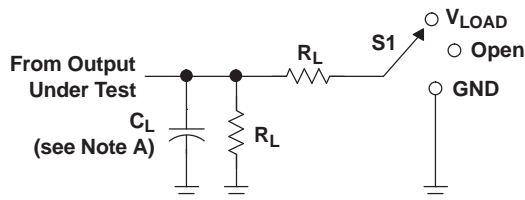


Figure 4. On-State Switch Leakage-Current Test Circuit

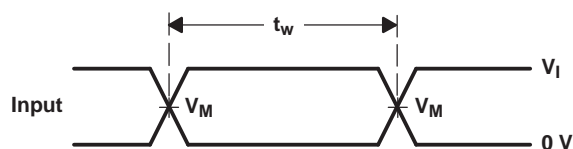
PARAMETER MEASUREMENT INFORMATION (continued)



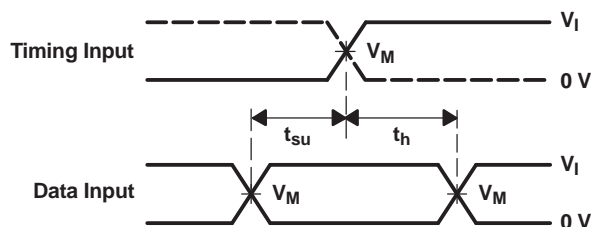
LOAD CIRCUIT

TEST	S1
$t_{PLH}/t_{PHL}$	Open
$t_{PLZ}/t_{PZL}$	$V_{LOAD}$
$t_{PHZ}/t_{PZH}$	GND

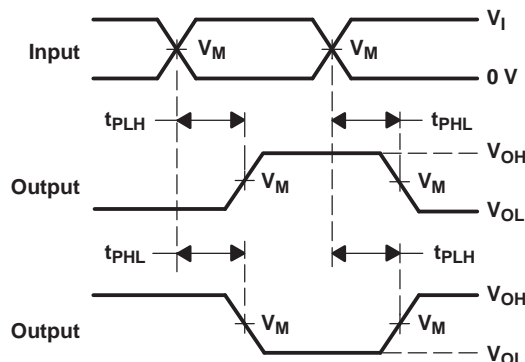
$V_{CC}$	INPUTS		$V_M$	$V_{LOAD}$	$C_L$	$R_L$	$V_{\Delta}$
	$V_I$	$t_r/t_f$					
$1.8\text{ V} \pm 0.15\text{ V}$	$V_{CC}$	$\leq 2\text{ ns}$	$V_{CC}/2$	$2 \times V_{CC}$	50 pF	500 $\Omega$	0.3 V
$2.5\text{ V} \pm 0.2\text{ V}$	$V_{CC}$	$\leq 2\text{ ns}$	$V_{CC}/2$	$2 \times V_{CC}$	50 pF	500 $\Omega$	0.3 V
$3.3\text{ V} \pm 0.3\text{ V}$	$V_{CC}$	$\leq 2.5\text{ ns}$	$V_{CC}/2$	$2 \times V_{CC}$	50 pF	500 $\Omega$	0.3 V
$5\text{ V} \pm 0.5\text{ V}$	$V_{CC}$	$\leq 2.5\text{ ns}$	$V_{CC}/2$	$2 \times V_{CC}$	50 pF	500 $\Omega$	0.3 V



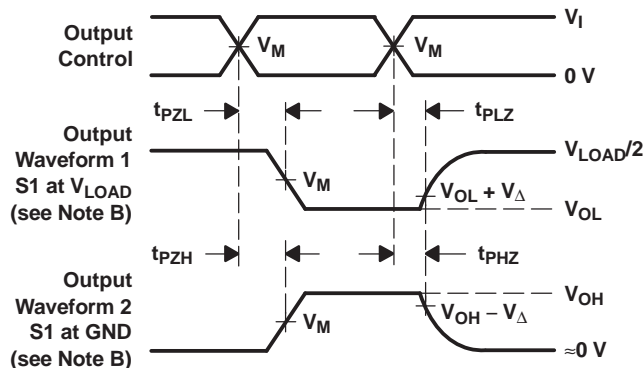
VOLTAGE WAVEFORMS  
PULSE DURATION



VOLTAGE WAVEFORMS  
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS  
PROPAGATION DELAY TIMES  
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS  
ENABLE AND DISABLE TIMES  
LOW- AND HIGH-LEVEL ENABLING

- NOTES:
- $C_L$  includes probe and jig capacitance.
  - Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10\text{ MHz}$ ,  $Z_O = 50\text{ }\Omega$ .
  - The outputs are measured one at a time, with one transition per measurement.
  - $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
  - All parameters and waveforms are not applicable to all devices.

Figure 5. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION (continued)

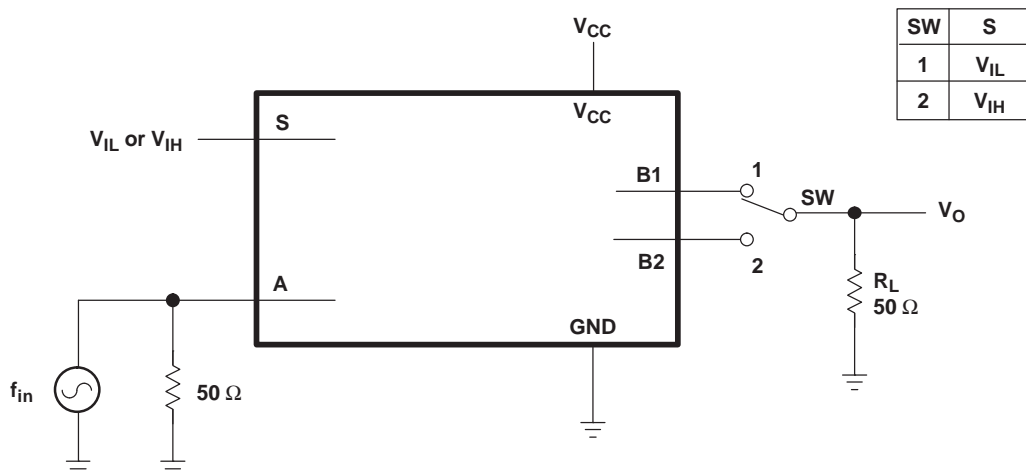


Figure 6. Frequency Response (Switch On)

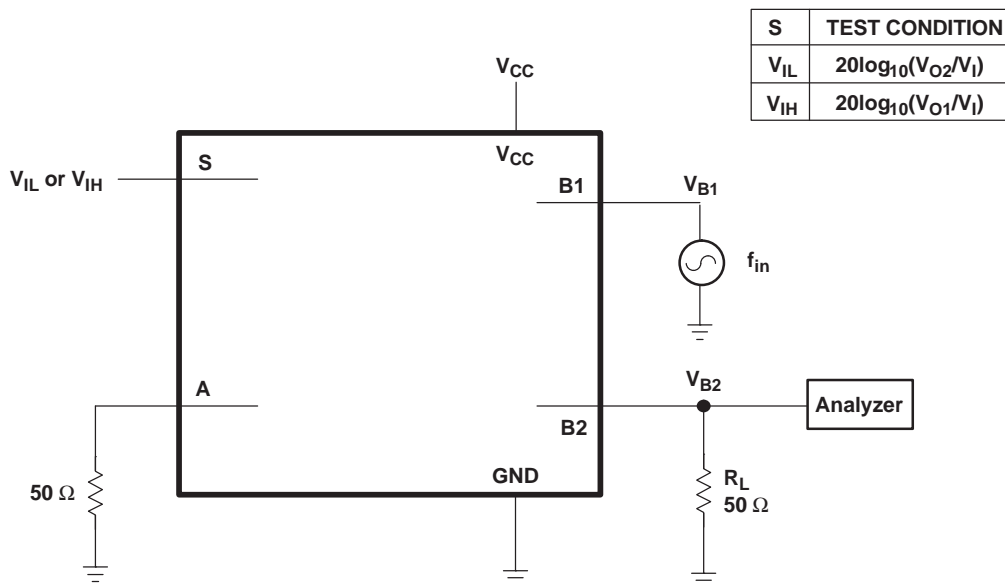


Figure 7. Crosstalk (Between Switches)

PARAMETER MEASUREMENT INFORMATION (continued)

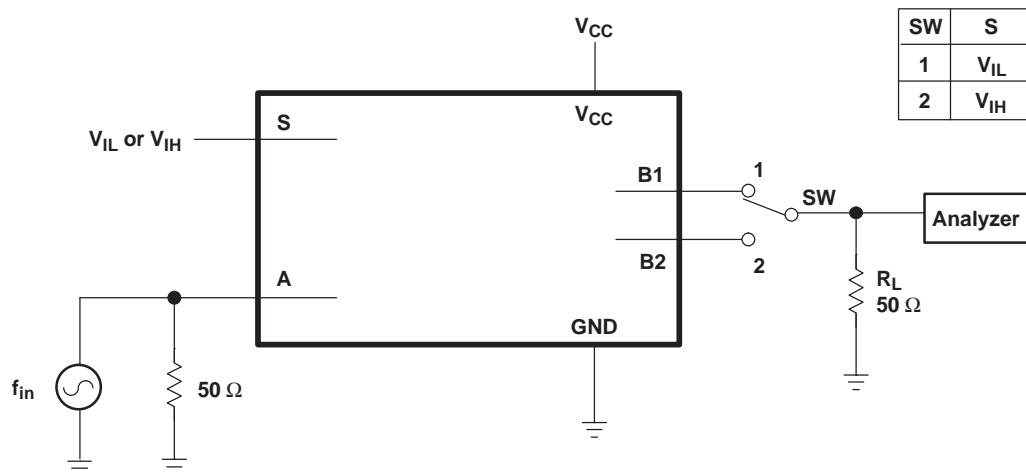


Figure 8. Feedthrough

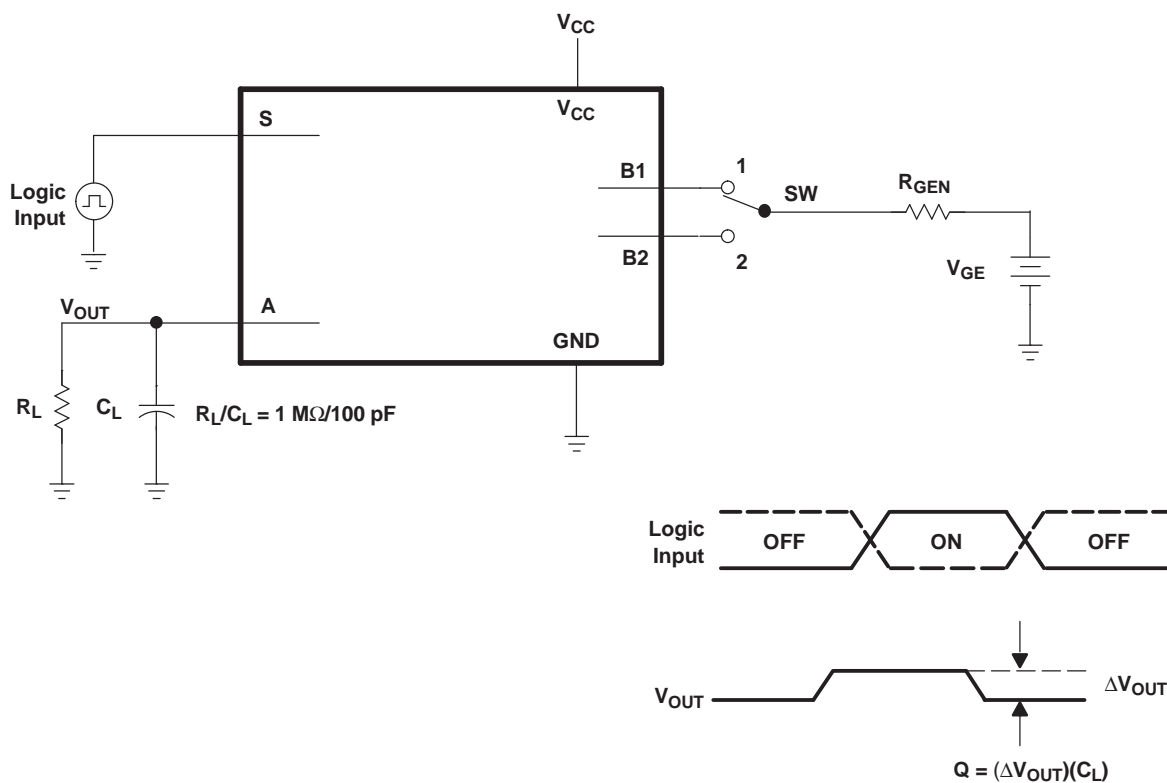


Figure 9. Charge-Injection Test

PARAMETER MEASUREMENT INFORMATION (continued)

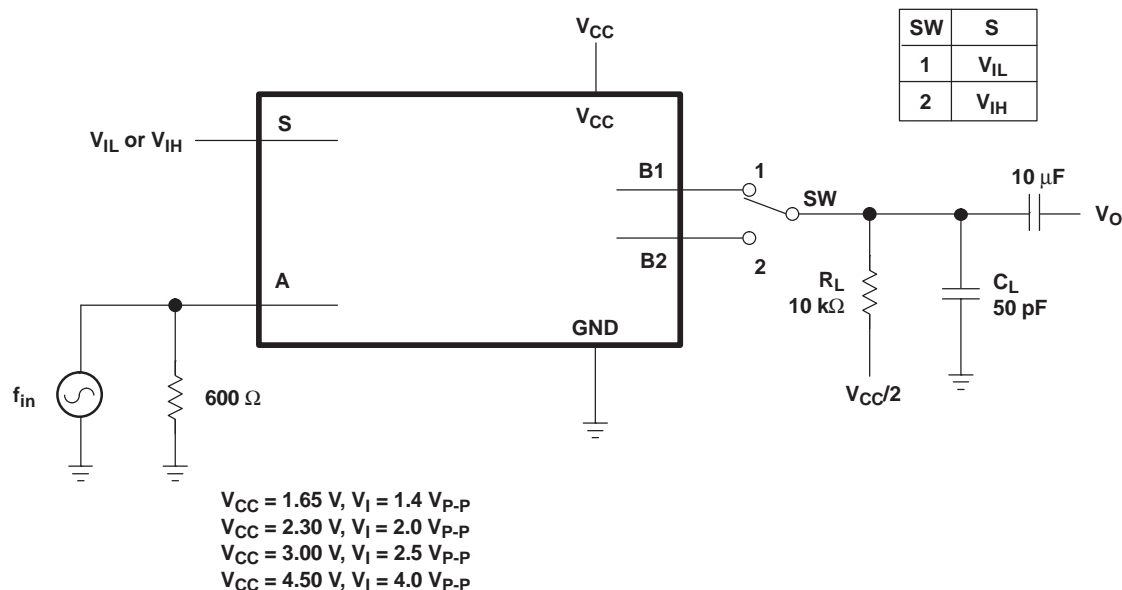


Figure 10. Total Harmonic Distortion

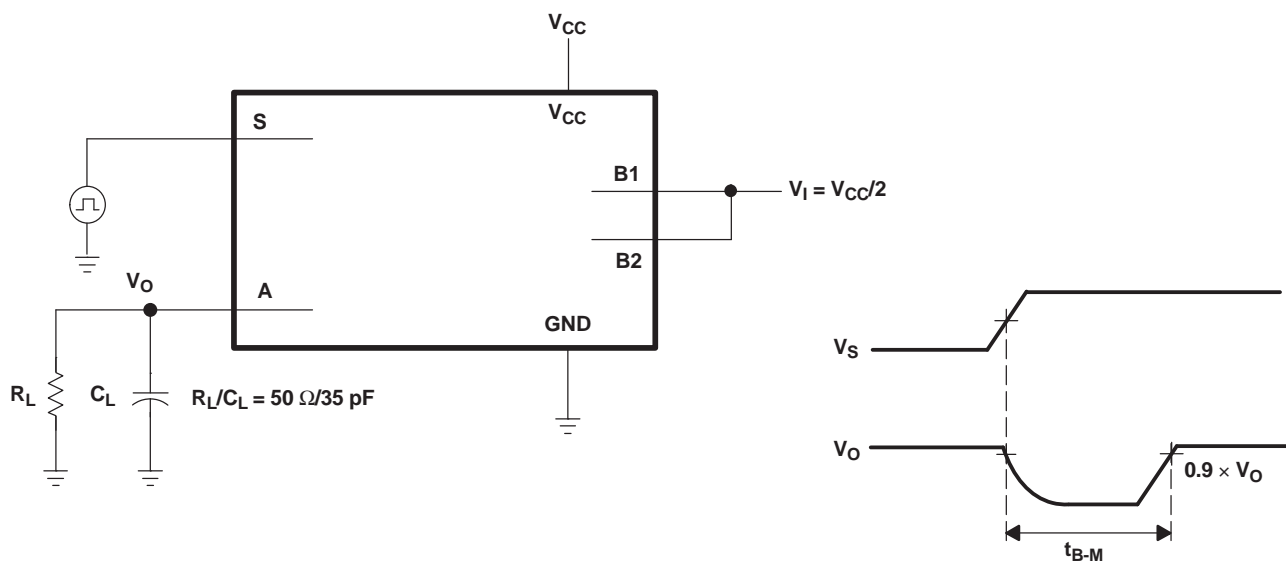


Figure 11. Break-Before-Make Internal Timing

## PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
1P1G3157QDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
1P1G3157QDCKRQ1	ACTIVE	SC70	DCK	6	3000	Pb-Free (RoHS)	NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBsolete:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

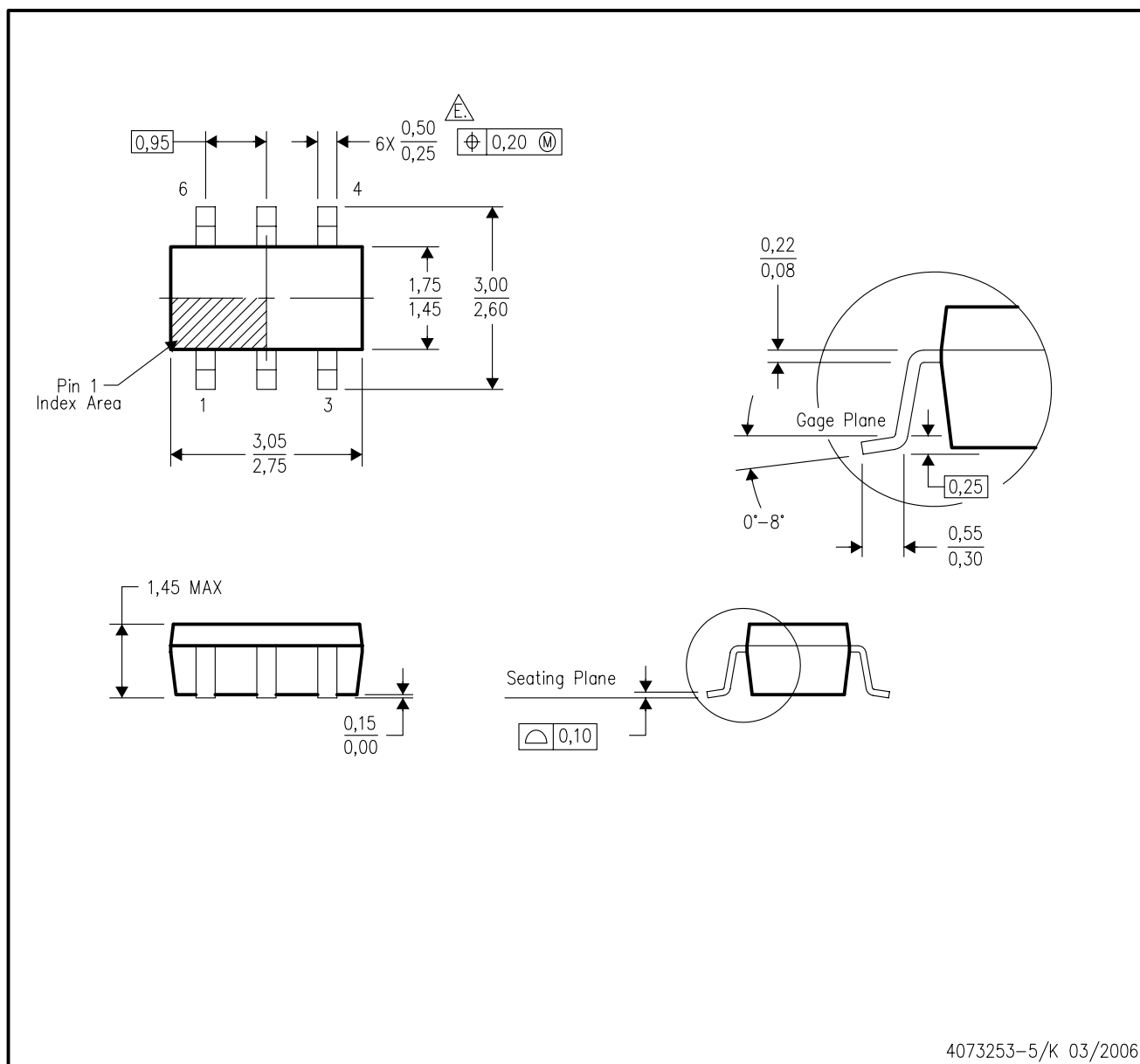
<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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## DBV (R-PDSO-G6)

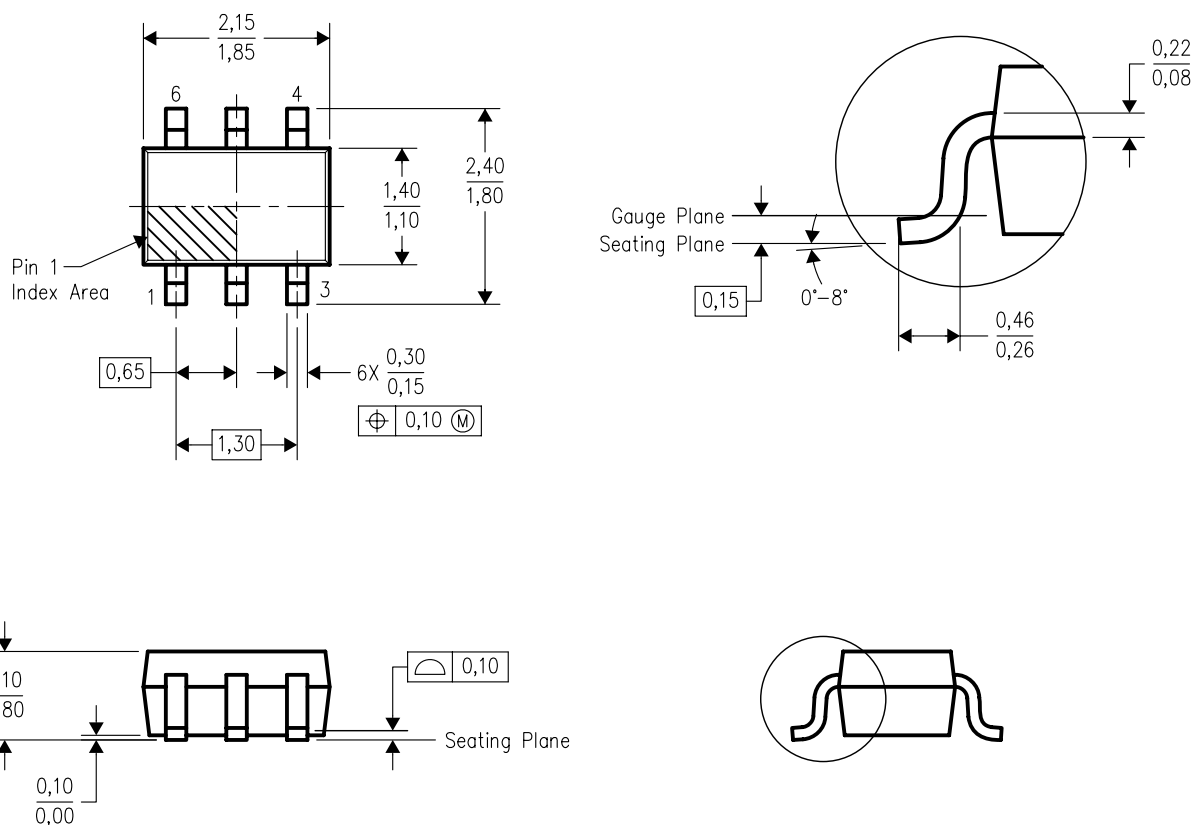
## PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- $\triangle$  Falls within JEDEC MO-178 Variation AB, except minimum lead width.

## DCK (R-PDSO-G6)

## PLASTIC SMALL-OUTLINE PACKAGE



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- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - Falls within JEDEC MO-203 variation AB.

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